



Quad, 12-/14-/16-Bit *nano*DACs with 5 ppm/°C On-Chip Reference, I²C Interface

AD5625R/AD5645R/AD5665R, AD5625/AD5665

FEATURES

Low power, smallest pin-compatible, quad nanoDACs AD5625R/AD5645R/AD5665R

12-/14-/16-bit nanoDACs

On-chip, 2.5 V, 5 ppm/°C reference in TSSOP

On-chip, 2.5 V, 10 ppm/°C reference in LFCSP

On-chip, 1.25 V, 10 ppm/°C reference in LFCSP

AD5625/AD5665

12-/16-bit nanoDACs

External reference only

3 mm × 3 mm 10-lead LFCSP and 14-lead TSSOP

2.7 V to 5.5 V power supply

Guaranteed monotonic by design

Power-on reset to zero scale/midscale

Per channel power-down

Hardware LDAC and CLR functions

I²C-compatible serial interface supports standard (100 kHz), fast (400 kHz), and high speed (3.4 MHz) modes

APPLICATIONS

Process control
Data acquisition systems
Portable battery-powered instruments
Digital gain and offset adjustment
Programmable voltage and current sources
Programmable attenuators

GENERAL DESCRIPTION

The AD5625R/AD5645R/AD5665R and AD5625/AD5665 members of the nanoDAC* family are low power, quad, 12-/14-/16-bit, buffered voltage-out DACs with/without an on-chip reference. All devices operate from a single 2.7 V to 5.5 V supply, are guaranteed monotonic by design, and have an I²C-compatible serial interface.

The AD5625R/AD5645R/AD5665R have an on-chip reference. The LFCSP versions of the AD56x5R have a 1.25 V or 2.5 V, 10 ppm/°C reference, giving a full-scale output range of 2.5 V or 5 V; the TSSOP versions of the AD56x5R have a 2.5 V, 5 ppm/°C reference, giving a full-scale output range of 5 V. The on-chip reference is off at power-up, allowing the use of an external reference. The internal reference is enabled via a software write. The AD5625/AD5665 require an external reference voltage to set the output range of the DAC.

The part incorporates a power-on reset circuit that ensures that the DAC output powers up to 0 V (POR = GND) or midscale (POR = $V_{\rm DD}$) and remains there until a valid write occurs. The on-chip precision output amplifier enables rail-to-rail output swing.

Rev. B

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FUNCTIONAL BLOCK DIAGRAMS

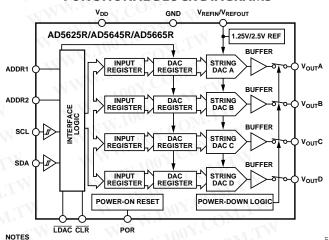


Figure 1. AD5625R/AD5645R/AD5665R

THE FOLLOWING PINS ARE AVAILABLE ONLY ON 14-LEAD PACKAGE:

ADDR2 | DAC CLR POR

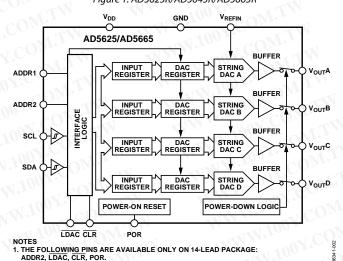


Figure 2. AD5625/AD5665

The AD56x5R/AD56x5 use a 2-wire I²C-compatible serial interface that operates in standard (100 kHz), fast (400 kHz), and high speed (3.4 MHz) modes.

Table 1. Related Devices

Part No.	Description
AD5025/AD5045/AD5065	Dual 12-/14-/16-bit DACs
AD5624R/AD5644R/AD5664R, AD5624/AD5664	Quad SPI 12-/14-/16-bit DACs, with/without internal reference
AD5627R/AD5647R/AD5667R, AD5627/AD5667	Dual I ² C 12-/14-/16-bit DACs, with/without internal reference
AD5666	Quad SPI 16-bit DAC with internal reference

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3/07—Revision 0: Initial Version

SPECIFICATIONS

SPECIFICATIONS—AD5665R/AD5645R/AD5625R

 $V_{DD} = 2.7 \ V \ to \ 5.5 \ V; \\ R_L = 2 \ k\Omega \ to \ GND; \\ C_L = 200 \ pF \ to \ GND; \\ V_{REFIN} = V_{DD}; \\ all \ specifications \ T_{MIN} \ to \ T_{MAX}, \\ unless \ otherwise \ noted.$

Table 2.

	MM	A Grad	U.	LITY	B Grade		100	· OM:TW
Parameter	Min	Тур	Max	Min	Тур	Max	Unit	Test Conditions/Comments ¹
STATIC PERFORMANCE ²	14,			OM:			WW.10	COM.
AD5665R	W			Town:			- TX 1	OX. CMITW
Resolution	~1			16			Bits	OOY.CO. TW
Relative Accuracy	7			COM	±8	±16	LSB	COM
Differential Nonlinearity	-					±1	LSB	Guaranteed monotonic by design
AD5645R				V.CO			MW	TOOY.CO. TY
Resolution				14			Bits	M.To. COM.
Relative Accuracy				01.	±2	±4	LSB	W.1001.
Differential Nonlinearity	Ų.			MY.C		±0.5	LSB	Guaranteed monotonic by design
AD5625R	T			-7			- 1	M. In COM.
Resolution	12			12			Bits	W.100 1. COM.1
Relative Accuracy	W	±1	±4	4005	±0.5	±1	LSB	W TOOY.CO TITY
Differential Nonlinearity			±1	V.Too		±0.25	LSB	Guaranteed monotonic by design
Zero-Code Error	TW	2	10	-xi 100	2	10	mV	All 0s loaded to DAC register
Offset Error	TV	±1	±10	14.	±1.	±10	mV	WW TIOOY.
Full-Scale Error	M.r.	-0.1	±0.5	M.M.T.	-0.1	±0.5	% FSR	All 1s loaded to DAC register
Gain Error	T.1.	±0.1	±1.25	- xxi 1	±0.1	±1	% FSR	M. 100 r. CONT. I.
Zero-Code Error Drift	77	±2		M. M.	±2		μV/°C	WWW. 100X.CO.T.TW
Gain Temperature Coefficient	OM.	±2.5		WW	±2.5		ppm	Of FSR/°C
DC Power Supply Rejection Ratio	COM	-100		WW.	-100		dB	DAC code = midscale; $V_{DD} = 5 V \pm 10\%$
DC Crosstalk (External Reference)	COJ	15		WW	15		μV	Due to full-scale output change, $R_L = 2 k\Omega$ to GND or V_{DD}
	$^{\circ}$.CC	10		11/1	10		μV/mA	Due to load current change
		8			8		μV	Due to powering down (per channel)
DC Crosstalk (Internal Reference)	07.0	25			25		μV	Due to full-scale output change, $R_L = 2 k\Omega$ to GND or V_{DD}
	00 7.	20			20		μV/mA	Due to load current change
	1003	10			10		μV	Due to powering down (per channel)
OUTPUT CHARACTERISTICS ³	. >	V.CO	W		WW	44	V.Co.	TW WW 100Y.
Output Voltage Range	0		V_{DD}	0		V_{DD}	V . CO	Internal reference disabled
	0		2×			2×	001.	Internal reference enabled
	W.r.		V_{REF}	W		V_{REF}	ONY.CL	TW WW 100
Capacitive Load Stability	σv^{1}	2		- 1	2		nF	R _L = ∞
	- ×1	10		LIN	10		nF	$R_L = 2 k\Omega$
DC Output Impedance	MM	0.5		W	0.5		Ω	WITH WITH
Short-Circuit Current	TANV	30		V. 2	30		mA	$V_{DD} = 5 V$
Power-Up Time		4.100	N.CO	M.T.V	4 N	W	μs	Coming out of power-down mode; $V_{DD} = 5 \text{ V}$
REFERENCE INPUTS	1	VW.10	7 (Mr.	***	_ «T	M. To.	A COM.
Reference Current	W	210	260	T.Mo.	210	260	μΑ	$V_{REF} = V_{DD} = 5.5 V$
Reference Input Range	0.75		V_{DD}	0.75		V_{DD}	V	10 X . CO.
Reference Input Impedance	4	26		COM	26		kΩ	
REFERENCE OUTPUT (1.25 V)		N	1007		LILY		NA T	
Output Voltage	1.247		1.253	1.247		1.253	٧	At ambient
Reference TC ³		±10		1 CO	±10		ppm/°C	
Output Impedance		7.5		11.	7.5		kΩ	

	A Grad	de	B Gr	ade	A CONT	TW
Parameter	Min Typ	Max	Min Typ	Max	Unit	Test Conditions/Comments ¹
REFERENCE OUTPUT (2.5 V)	W 10	01.	W.I.	44	W.100	$V_{DD} = 4.5 \text{ V to } 5.5 \text{ V}$
Output Voltage	2.495	2.505	2.495	2.505	V	At ambient
Reference TC ³	±10		±5	±10	ppm/°C	COM
Output Impedance	7.5		7.5		kΩ	COMIT
LOGIC INPUTS (ADDRx, CLR,	MM	Anny.	WILL		NA .	001. TW
LDAC, POR) ³	TWV		$CO_{M_{I}}$		WW.	OV.COM
I _{IN} , Input Current	N ·	±1	COMIT	±1	μΑ	100 x COW. 1
V _{INL} , Input Low Voltage	WW	$0.15 \times V_{DD}$	1.00	$0.15 \times V_{DD}$	V	100Y. OM.TW
V _{INH} , Input High Voltage	$0.85 \times V_{DD}$		$0.85 \times V_{DD}$		V	V. ONY.COM. TW
C _{IN} , Pin Capacitance	2		2		pF	W.Ing COM.
V _{HYST} , Input Hysteresis	$0.1 \times V_{DD}$		$0.1 \times V_{DD}$		V	100 Y. ON. TW
LOGIC INPUTS (SDA, SCL) ³	N ×	MAN	ON COR	TW	W	ATT CONTRACTOR
I _{IN} , Input Current		±1	100 - 00	±1	μΑ	MM.In. COM.
V _{INL} , Input Low Voltage		$0.3 \times V_{DD}$	1007	$0.3 \times V_{DD}$	V	1,100 r. COM'IL
V _{INH} , Input High Voltage	$0.7 \times V_{DD}$		$0.7 \times V_{DD}$		٧	WY WALLEY
C _{IN} , Pin Capacitance	2		2		pF	MAN. TO COM.
V _{HYST} , Input Hysteresis	$0.1 \times V_{DD}$		$0.1 \times V_{DD}$		V	High speed mode
WWW. COV.CO	$0.05 \times V_{DD}$		$0.05 \times V_{DD}$		V	Fast mode
LOGIC OUTPUTS (SDA) ³	Mi	- 41	MAN	1 COMP.	~XX	M.M. COm
V _{OL} , Output Low Voltage	ON TW	0.4	100°	0.4	V	I _{SINK} = 3 mA
WWW.	WT	0.6	100	0.6	V	I _{SINK} = 6 mA
Floating-State Leakage Current	CONTA	±1	WWW.I	±10N	μΑ	WWW.100Y.COM.
Floating-State Output Capacitance	2		2		pF	WWW.100V.COM
POWER REQUIREMENTS	T.M.T	A4	111	100 1.	OW.LA	777.100
V_{DD}	2.7	5.5	2.7	5.5	٧	N WW. 100X.Co.
I _{DD} (Normal Mode) ⁴	TOM.		TAIN!		CO_{Mrr}	$V_{IH} = V_{DD}$, $V_{IL} = GND$, full-scale loaded
$V_{DD} = 4.5 \text{ V to } 5.5 \text{ V}$	1.0	1.16	1.0	1.16	mA	Internal reference off
$V_{DD} = 2.7 \text{ V to } 3.6 \text{ V}$	0.9	1.05	0.9	1.05	mA	Internal reference off
$V_{DD} = 4.5 \text{ V to } 5.5 \text{ V}$	1.9	2.14	1.9	2.14	mA	Internal reference on
$V_{DD} = 2.7 \text{ V to } 3.6 \text{ V}$	1.4	1.59	1.4	1.59	mA	Internal reference on
I _{DD} (All Power-Down Modes) ⁵	. OUX.Cr		1		OXICO	TIN WW TIOON
$V_{DD} = 2.7 \text{ V to } 5.5 \text{ V}$	0.48	071.	0.48	1	μA	$V_{IH} = V_{DD}$, $V_{IL} = GND$ (LFCSP)
$V_{DD} = 3.6 \text{ V to } 5.5 \text{ V}$	0.48	4.1.1	0.48	1	μA	$V_{IH} = V_{DD}$, $V_{IL} = GND$ (TSSOP)

¹ Temperature range of A and B grades is -40°C to +105°C. ² Linearity calculated using a reduced code range: AD5665R (Code 512 to Code 65,024), AD5645R (Code 128 to Code 16,256), AD5625R (Code 32 to Code 4064). Output unloaded.

³ Guaranteed by design and characterization; not production tested.

⁴ Interface inactive. All DACs active. DAC outputs unloaded.

 $^{^5}$ All DACs powered down. Power-down function is not available on 14-lead TSSOP parts when the part is powered with V_{DD} < 3.6 V.

SPECIFICATIONS—AD5665/AD5625

 V_{DD} = 2.7 V to 5.5 V; R_L = 2 k Ω to GND; C_L = 200 pF to GND; V_{REFIN} = V_{DD} ; all specifications T_{MIN} to T_{MAX} , unless otherwise noted.

Table 3.

COM: 10	COM	B Grade	2 .41	MN.J	A COM
Parameter	Min	Тур	Max	Unit 10	Test Conditions/Comments ¹
STATIC PERFORMANCE ²	1007.00	VIIV		1	107.0 M.TW
AD5665	·LOVCO			WWW	ony.Com
Resolution	16			Bits	Too COM.
Relative Accuracy	1007.0	±8	±16	LSB	1007. OM.TW
Differential Nonlinearity	W. J.		±1	LSB	Guaranteed monotonic by design
AD5625	VW.100			TXN	N.Ing COM.
Resolution	12 100			Bits	M.1001.
Relative Accuracy	1111	±0.5	±1	LSB	TW. Co. TW
Differential Nonlinearity	WW.100		±0.25	LSB	Guaranteed monotonic by design
Zero-Code Error	10	2	10	mV	All 0s loaded to DAC register
Offset Error	MM.	±1.	±10	mV	WWW. 100Y.CO. TETY
Full-Scale Error	L.WW.	-0.1	±0.5	% FSR	All 1s loaded to DAC register
Gain Error	W.	±0.1	±1	% FSR	M. TM. 100 T. COW. I.
Zero-Code Error Drift	MM	±2		μV/°C	WW 100Y.CONITW
Gain Temperature Coefficient	VWV	±2.5		ppm	Of FSR/°C
DC Power Supply Rejection Ratio	N. T.	-100		dB	DAC code = midscale; $V_{DD} = 5 V \pm 10\%$
DC Crosstalk (External Reference)	MM	15		μV	Due to full-scale output change, $R_L = 2 \text{ k}\Omega$ to GND or V_{DD}
	N.	10		μV/mA	Due to load current change
	W	8		μV	Due to powering down (per channel)
DC Crosstalk (Internal Reference)	N V	25		μV	Due to full-scale output change, $R_L = 2 k\Omega$ to GND or V_{DD}
	WV.	20		μV/mA	Due to load current change
	L	10		μV	Due to powering down (per channel)
OUTPUT CHARACTERISTICS ³	3/4	M.	-XI 100 x.	T.Mor	11. 100, COM.
Output Voltage Range	0		V_{DD}	٧	WW 1007.
Capacitive Load Stability	1	2		nF	R _L = ∞
	N.T.V	10		nF	$R_L = 2 k\Omega$
DC Output Impedance	WT	0.5		Ω	LIW WW. 100X.
Short-Circuit Current	OM.	30		mA ($V_{DD} = 5 V$
Power-Up Time	W.T.W	4		μs	Coming out of power-down mode; $V_{DD} = 5 \text{ V}$
REFERENCE INPUTS	WT		MAN	1001.0	M.TW W" 1001.
Reference Current	COMP.	210	260	μΑ	$V_{REF} = V_{DD} = 5.5 \text{ V}$
Reference Input Range	0.75		V_{DD}	V	OW.
Reference Input Impedance	Y CONT	26		kΩ	W.1001
LOGIC INPUTS (ADDRx, CLR, LDAC, POR) ³	CON	r VV	WW	100	Co. IN MAL 100
I _{IN} , Input Current	COM.		±1	μA	COM.
V _{INL} , Input Low Voltage	MY.		$0.15 \times V_{DD}$	V _{**1} 100	1. OM.TW W. 101
V _{INH} , Input High Voltage	$0.85 \times V_{DD}$			٧	DY.CO. THE WAY
C _{IN} , Pin Capacitance	100	2		pF	COM.
V _{HYST} , Input Hysteresis	$0.1 \times V_{DD}$			V	001. ONITA
LOGIC INPUTS (SDA, SCL) ³	. OUT C		W	MAG	1007.CTW
I _{IN} , Input Current	1 Jus = 1 C		±1	μΑ	COMP
V _{INL} , Input Low Voltage	100 X.C		$0.3 \times V_{DD}$	V	N.700 r.
V _{INH} , Input High Voltage	$0.7 \times V_{DD}$		TW	V	
C _{IN} , Pin Capacitance	W.100	201		pF	
	41 (00)				1
V _{HYST} , Input Hysteresis	$0.1 \times V_{DD}$			V	High speed mode

A COMP	N.Co	B Grade	e W	W 41.	Y.Co.
Parameter	Min	Тур	Max	Unit	Test Conditions/Comments ¹
LOGIC OUTPUTS (SDA) ³	1007.	M.I.		-TVV.1	N. COM.
Vol., Output Low Voltage	ONY.CO		0.4	V	I _{SINK} = 3 mA
	A CO		0.6	V	$I_{SINK} = 6 \text{ mA}$
Floating-State Leakage Current	111001.		±1	μΑ	.100 COM.1
Floating-State Output Capacitance	100X.	2		pF	T100Y.COMITW
POWER REQUIREMENTS	W.	$CO_{D_{2}}$	TIN		TY CO
V_{DD}	2.7		5.5	٧	M. Ing COM.
I _{DD} (Normal Mode) ⁴	100				$V_{IH} = V_{DD}$, $V_{IL} = GND$, full-scale loaded
$V_{DD} = 4.5 \text{ V to } 5.5 \text{ V}$	MW.L	1.0	1.16	mA 🕥	NW. CON. COM
$V_{DD} = 2.7 \text{ V to } 3.6 \text{ V}$	W.10	0.9	1.05	mA	M. Joo COM.
I _{DD} (All Power-Down Modes) ⁵	1				100x. CM.TW
$V_{DD} = 2.7 \text{ V to } 5.5 \text{ V}$	MMM.	0.48	9	μΑ	$V_{IH} = V_{DD}$, $V_{IL} = GND$ (LFCSP)
$V_{DD} = 3.6 \text{ V to } 5.5 \text{ V}$	W.	0.48	101	μΑ	$V_{IH} = V_{DD}$, $V_{IL} = GND$ (TSSOP)

¹ Temperature range of B grade is -40°C to +105°C.

² Linearity calculated using a reduced code range: AD5665 (Code 512 to Code 65,024), AD5625 (Code 32 to Code 4064). Output unloaded.

³ Guaranteed by design and characterization; not production tested.

⁴ Interface inactive. All DACs active. DAC outputs unloaded.

 $^{^{5}}$ All DACs powered down. Power-down function is not available on 14-lead TSSOP parts when the part is powered with V_{DD} < 3.6 V.

AC CHARACTERISTICS

 $V_{DD} = 2.7 \text{ V}$ to 5.5 V; $R_L = 2 \text{ k}\Omega$ to GND; $C_L = 200 \text{ pF}$ to GND; $V_{REFIN} = V_{DD}$; all specifications T_{MIN} to T_{MAX} , unless otherwise noted.

Parameter ^{1,2}	Min	Тур	Max	Unit	Test Conditions/Comments ³
Output Voltage Settling Time	1 100		Wille		M. Ina. COM.
AD5625R/AD5625		3	4.5	μs	1/4 to 3/4 scale settling to ±0.5 LSB
AD5645R	M.Jak	3.5	5	μs	1/4 to 3/4 scale settling to ±0.5 LSB
AD5665R/AD5665	11	4	7	μs	1/4 to 3/4 scale settling to ±2 LSB
Slew Rate	1111.2	1.8		V/µs	WWW. ONY. CO. TW
Digital-to-Analog Glitch Impulse	ATVI 1				1 LSB change around major carry
TW. CO.		15		nV-s	LFCSP
		5		nV-s	TSSOP
Digital Feedthrough	1	0.1		nV-s	COM. I
Reference Feedthrough	WW	-90		dB	$V_{REF} = 2 V \pm 0.1 V p-p$, frequency 10 Hz to 20 MHz
Digital Crosstalk		0.1		nV-s	MMM. TO COMP
Analog Crosstalk	111.	1 1		nV-s	External reference
NWW. COM	11/1	4		nV-s	Internal reference
DAC-to-DAC Crosstalk		1111		nV-s	External reference
		4		nV-s	Internal reference
Multiplying Bandwidth	-	340		kHz	$V_{REF} = 2 V \pm 0.1 V p-p$
Total Harmonic Distortion		-80		dB	$V_{REF} = 2 V \pm 0.1 V p-p$, frequency = 10 kHz
Output Noise Spectral Density		120		nV/√Hz	DAC code = midscale, 1 kHz
COM.		100		nV/√Hz	DAC code = midscale, 10 kHz
Output Noise		15		μV р-р	0.1 Hz to 10 Hz

Guaranteed by design and characterization; not production tested.

WWW.100Y.COM.

 $^{^{2}}$ See the Terminology section.

³ Temperature range is −40°C to +105°C, typical @ 25°C.

1²C TIMING SPECIFICATIONS

 V_{DD} = 2.7 V to 5.5 V; all specifications T_{MIN} to T_{MAX} , f_{SCL} = 3.4 MHz, unless otherwise noted.

Table 5.

Parameter	Test Conditions ²	Min	Max	Unit	Description
f _{SCL} ³	Standard mode	1001.	100	kHz	Serial clock frequency
	Fast mode	. LOOY.CC	400	kHz	TI 100Y.COM.TW
	High speed mode, $C_B = 100 \text{ pF}$	V C	3.4	MHz	INN. TOWN.
	High speed mode, $C_B = 400 \text{ pF}$	W.100 r.	1.7	MHz	M. M. Too COM. T.
t_1	Standard mode	4		μs	t _{нібн} , SCL high time
	Fast mode	0.6		Nμs	MAN CON COR
	High speed mode, $C_B = 100 \text{ pF}$	60		ns	COM.
	High speed mode, $C_B = 400 \text{ pF}$	120		ns	WW. 1007.0 M.TW
t_2	Standard mode	4.7		μs	t _{LOW} , SCL low time
	Fast mode	1.3		μs	COM
	High speed mode, $C_B = 100 \text{ pF}$	160		ns	WW. TI 100Y.
	High speed mode, $C_B = 400 \text{ pF}$	320		ns	WWW. OUY.CO. TW
t₃	Standard mode	250		ns	t _{SU;DAT} , data setup time
WW	Fast mode	100		ns	M. 1001.
	High speed mode	10		ns	WWW. DOV.CO. TW
t ₄	Standard mode	0	3.45	μs	t _{HD;DAT} , data hold time
· ·	Fast mode	0	0.9	μs	William and the state of the st
	High speed mode, $C_B = 100 \text{ pF}$	0	70	ns	TW WWW. ONY.CO. TW
	High speed mode, $C_B = 400 \text{ pF}$	0	150	ns	NW.100 COM.
t 5	Standard mode	4.7	100	μs	tsu;sta, setup time for a repeated start condition
•5	Fast mode	0.6		μς	(30,51A) Setup time for a repeated start condition
	High speed mode	160		ns	VI COM.
$t_{\scriptscriptstyle 6}$	Standard mode	4		μs	t _{HD;STA} , hold time (repeated) start condition
•0	Fast mode	0.6		μs	thus, stay from time (repeated) start container
	High speed mode	160		ns C	ONT.
t ₇	Standard mode	4.7		μs	t _{BUF} , bus-free time between a stop and a start
()	Standard Mode	4.7		μ3	condition
	Fast mode	1.3		μs	CONT. MAN. TO CO.
t ₈	Standard mode	4		μs	t _{sU;sто} , setup time for a stop condition
-	Fast mode	0.6		μs	Y CONTRACTOR TO THE STATE OF TH
	High speed mode	160		ns	COM.
t ₉	Standard mode	TIM	1000	ns 1	t _{RDA} , rise time of SDA signal
•,	Fast mode	COM	300	ns	MAN TOOK
	High speed mode, $C_B = 100 \text{ pF}$	10	80	ns	COM.
	High speed mode, $C_B = 400 \text{ pF}$	20	160	ns	101. COM. TV
t ₁₀	Standard mode	CON.	300	ns	t _{FDA} , fall time of SDA signal
C 10	Fast mode	COM	300	ns	troa, rail time of 5D/t signal
	High speed mode, $C_B = 100 \text{ pF}$	10	80	ns	2 1001. OM: IN.
	High speed mode, $C_B = 100 \text{ pf}$	20	160	ns	WT YOU'S
+	Standard mode	20	1000		t _{RCL} , rise time of SCL signal
t ₁₁	Fast mode	1007.	300	ns	treet, rise time of SCL signal
	High speed mode, $C_B = 100 \text{ pF}$	10 V.C	300 40	ns	A 100 X'CO TAM MM.
	High speed mode, $C_B = 100 \text{ pF}$ High speed mode, $C_B = 400 \text{ pF}$	10		ns	MAN. TO COM.
		20	80	ns	
t _{11A}	Standard mode	L'ant	1000	ns	t _{RCL1} , rise time of SCL signal after a repeated start condition and after an acknowledge bit
	Fast mode	VA 100	300	o nc	condition and after an acknowledge bit
	High speed mode, $C_B = 100 \text{ pF}$	10 100	80	ns	NA .
				ns	
	High speed mode, $C_B = 400 \text{ pF}$	20	160	ns	

Parameter	Test Conditions ²	Min	Max	Unit	Description
t ₁₂	Standard mode	OM	300	ns	t _{FCL} , fall time of SCL signal
	Fast mode	OMITY	300	ns	ON: I
	High speed mode, $C_B = 100 \text{ pF}$	10	40	ns	MOY.CO TILTY
	High speed mode, $C_B = 400 \text{ pF}$	20	80	ns	ON COMP.
t ₁₃	Standard mode	10		ns	LDAC pulse width low
	Fast mode	10		ns	100Y.C. M.TW
	High speed mode	10 CON		ns	N. TW
t ₁₄	Standard mode	300		ns	Falling edge of ninth SCL clock pulse of last byte of a valid write to LDAC falling edge
	Fast mode	300		ns	M. COM.
	High speed mode	30		ns	NW.100 COM.
t ₁₅	Standard mode	20		ns	CLR pulse width low
	Fast mode	20		ns	WWW. CO. TW
	High speed mode	20		ns	MANN TO COM.
t _{SP} ⁴	Fast mode	0 100	50	ns	Pulse width of spike suppressed
	High speed mode	0	10	ns	WW TOOK CO TITY

See Figure 3. High speed mode timing specification applies only to the AD5625RBRUZ-2/AD5625RBRUZ-2REEL7 and AD5665RBRUZ-2/AD5665RBRUZ-2REEL7.

⁴ Input filtering on the SCL and SDA inputs suppresses noise spikes that are less than 50 ns for fast mode or less than 10 ns for high speed mode.

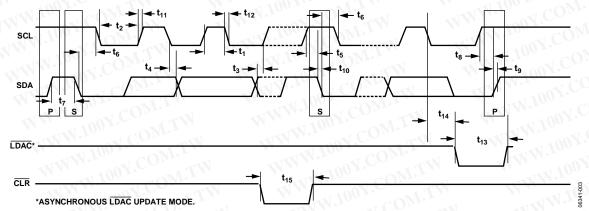


Figure 3. 2-Wire Serial Interface Timing Diagram

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 $^{^{2}}$ C_B refers to the capacitance on the bus line.

³ The SDA and SCL timing is measured with the input filters enabled. Switching off the input filters improves the transfer rate but has a negative effect on the EMC behavior of the part.

ABSOLUTE MAXIMUM RATINGS

 $T_A = 25$ °C, unless otherwise noted.

Table 6.

Vout to GND -0.3 VREFIN/VREFOUT tO GND -0.3	3 V to +7 V 3 V to V _{DD} + 0.3 V 3 V to V _{DD} + 0.3 V
V _{REFIN} /V _{REFOUT} to GND -0.3	
	$3 \text{ V to V}_{DD} + 0.3 \text{ V}$
Digital Input Voltage to GND -0.3	
	$3 \text{ V to V}_{DD} + 0.3 \text{ V}$
Operating Temperature Range, Industrial –40	0°C to +105°C
Storage Temperature Range –65	5°C to +150°C
Junction Temperature (T _J maximum) 150)°C
Power Dissipation (T _J)	$max - T_A)/\theta_{JA}$
θ _{JA} Thermal Impedance	
LFCSP_WD (4-Layer Board) 61°0	C/W
TSSOP 150).4°C/W
Reflow Soldering Peak Temperature, 260 RoHS Compliant	0°C ± 5°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

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PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS



Figure 4. Pin Configuration (14-Lead TSSOP), R Suffix Version

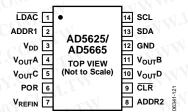


Figure 5. Pin Configuration (14-Lead TSSOP)

Figure 6. Pin Configuration (10-Lead LFCSP), R Suffix Version

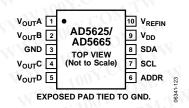


Figure 7. Pin Configuration (10-Lead LFCSP)

Table 7. Pin Function Descriptions

Pin N	ımber	COn	N. M.M. WAY.CO. T.M.	
14-Lead	10-Lead	Mnemonic	Description	
1	N/A	LDAC	Pulsing this pin low allows any or all DAC registers to be u This allows simultaneous update of all DAC outputs. Alter low.	
2	N/A	ADDR1	Three-State Address Input. Sets the two least significant be (see Table 9).	oits (Bit A1, Bit A0) of the 7-bit slave address
3	9	V _{DD}	Power Supply Input. These parts can be operated from 2. decoupled with a 10 μF capacitor in parallel with a 0.1 μF	
4	1	V _{оит} А	Analog Output Voltage from DAC A. The output amplifier	r has rail-to-rail operation.
5	4	VoutC	Analog Output Voltage from DAC C. The output amplifier	has rail-to-rail operation.
6	N/A	POR	Power-On Reset Pin. Tying the POR pin to GND powers up powers up the part to midscale.	o the part to 0 V. Tying the POR pin to V_{DD}
7	10	VREFIN/VREFOUT	The AD56x5R have a common pin for reference input and reference, this is the reference output pin. When using an input pin. The default for this pin is as a reference input. (are only available on R suffix versions.) The AD56x5 has a	n external reference, this is the reference The internal reference and reference output
8	N/A	ADDR2	Three-State Address Input. Sets Bit A3 and Bit A2 of the 7-	-bit slave address (see Table 9).
9	N/A	CLR WWW.	Asynchronous Clear Input. The CLR input is falling-edge s are ignored. When CLR is activated, zero scale is loaded to output to 0 V. The part exits clear code mode on the fallin byte of the valid write. If CLR is activated during a write seactivated during high speed mode, the part exits high speed	o all input and DAC registers. This clears the ig edge of the ninth clock pulse of the last equence, the write is aborted. If CLR is
10	5	V _{оит} D	Analog Output Voltage from DAC D. The output amplifier	r has rail-to-rail operation.
11	2	V _{оит} В	Analog Output Voltage from DAC B. The output amplifier	has rail-to-rail operation.
12	3	GND	Ground Reference Point for All Circuitry on the Part.	
13	8	SDA	Serial Data Line. This is used in conjunction with the SCL I input register. It is a bidirectional, open-drain data line the external pull-up resistor.	
14	7	SCL	Serial Clock Line. This is used in conjunction with the SDA input register.	line to clock data into or out of the 16-bit
N/A	6	ADDR	Three-State Address Input. Sets the two least significant be (see Table 8).	oits (Bit A1, Bit A0) of the 7-bit slave address
	EPAD		For the 10-lead LFCSP, the exposed pad must be tied to G	IND.
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			Rev. B Page 11 of 36	胜特力电子(上海) 86-21-34970699

TYPICAL PERFORMANCE CHARACTERISTICS

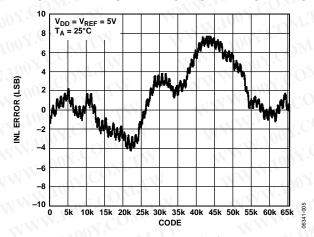


Figure 8. INL, AD5665, External Reference

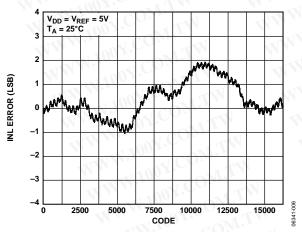


Figure 9. INL, AD5645R, External Reference

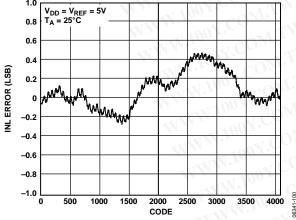


Figure 10. INL, AD5625, External Reference

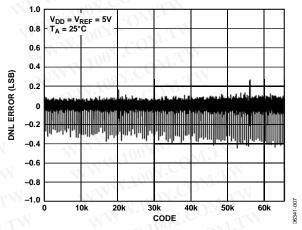


Figure 11. DNL, AD5665, External Reference

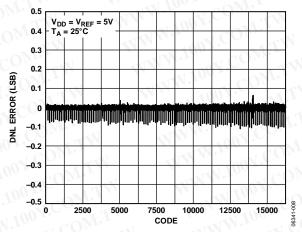


Figure 12. DNL, AD5645R, External Reference

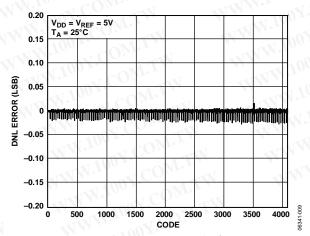


Figure 13. DNL, AD5625, External Reference

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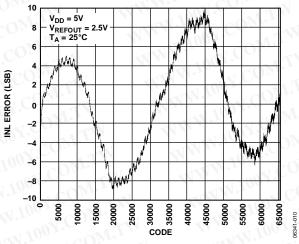


Figure 14. INL, AD5665R, 2.5 V Internal Reference

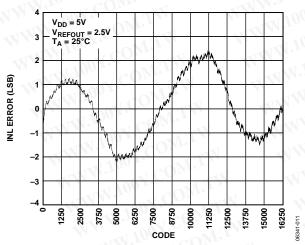


Figure 15. INL, AD5645R, 2.5 V Internal Reference

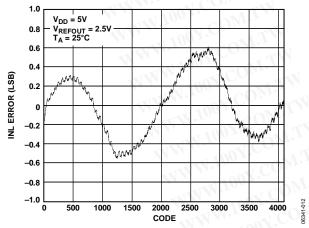


Figure 16. INL, AD5625R, 2.5 V Internal Reference

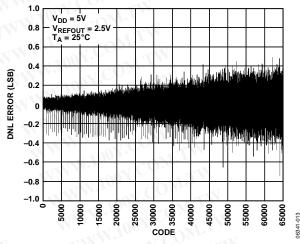


Figure 17. DNL, AD5665R, 2.5 V Internal Reference

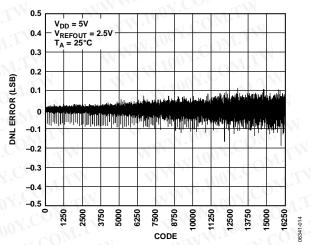


Figure 18. DNL, AD5645R, 2.5 V Internal Reference

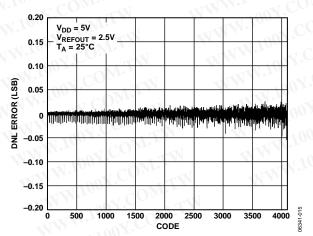


Figure 19. DNL, AD5625R, 2.5 V Internal Reference

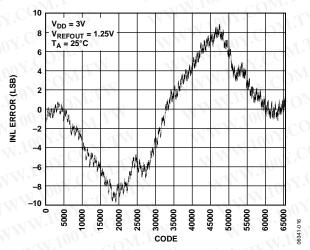


Figure 20. INL, AD5665R, 1.25 V Internal Reference

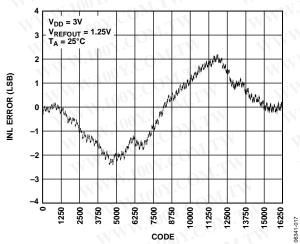


Figure 21. INL, AD5645R, 1.25 V Internal Reference

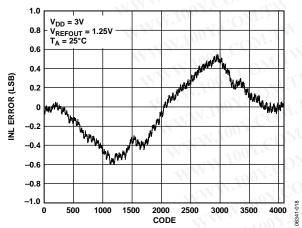


Figure 22. INL, AD5625R, 1.25 V Internal Reference

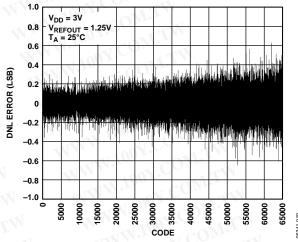


Figure 23. DNL, AD5665R, 1.25 V Internal Reference

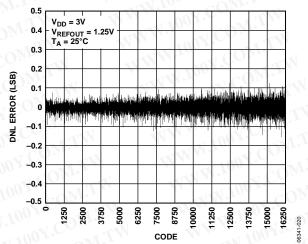


Figure 24. DNL, AD5645R, 1.25 V Internal Reference

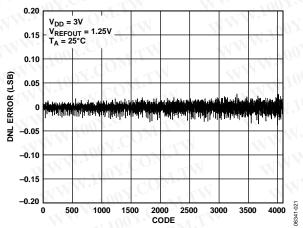


Figure 25. DNL, AD5625R, 1.25 V Internal Reference

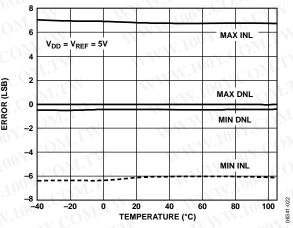


Figure 26. INL Error and DNL Error vs. Temperature

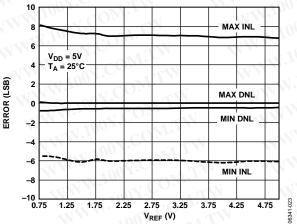


Figure 27. INL Error and DNL Error vs. VREF

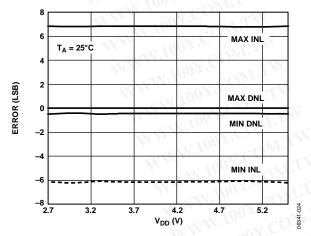


Figure 28. INL Error and DNL Error vs. Supply

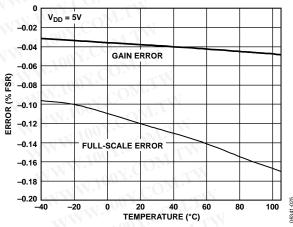


Figure 29. Gain Error and Full-Scale Error vs. Temperature

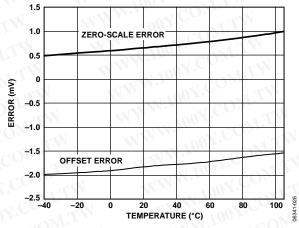


Figure 30. Zero-Scale Error and Offset Error vs. Temperature

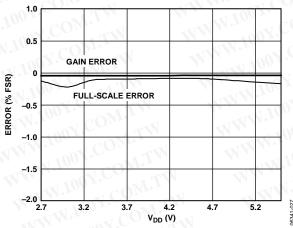


Figure 31. Gain Error and Full-Scale Error vs. Supply

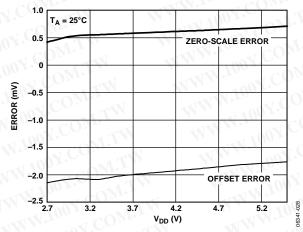


Figure 32. Zero-Scale Error and Offset Error vs. Supply

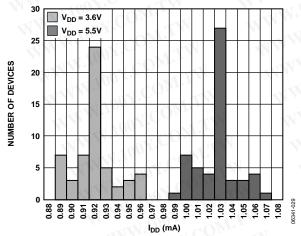


Figure 33. IDD Histogram with External Reference

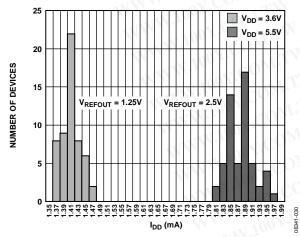


Figure 34. IDD Histogram with Internal Reference

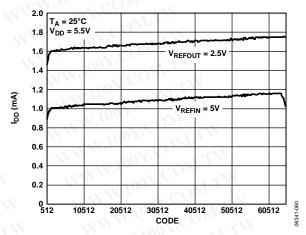


Figure 35. Supply Current vs. DAC Code

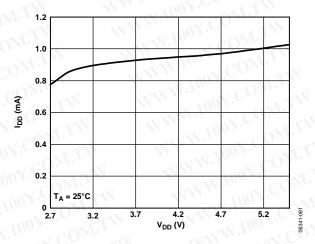


Figure 36. Supply Current vs. Supply

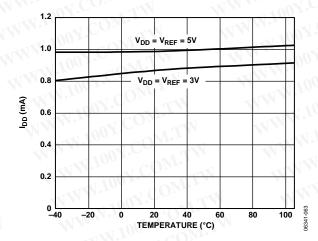


Figure 37. Supply Current vs. Temperature

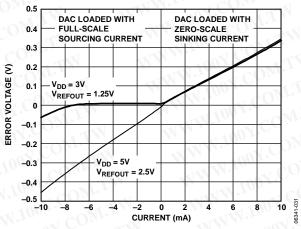


Figure 38. Headroom at Rails vs. Source and Sink

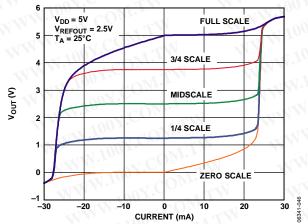


Figure 39. AD56x5R with 2.5 V Reference, Source and Sink Capability

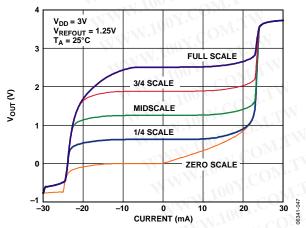


Figure 40. AD56x5R with 1.25 V Reference, Source and Sink Capability

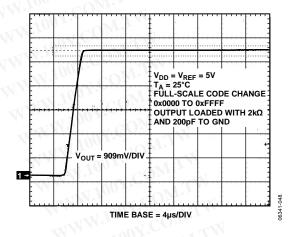


Figure 41. Full-Scale Settling Time, 5 V

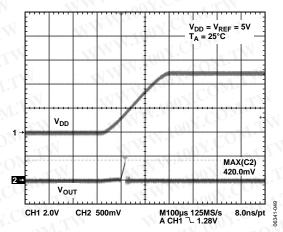


Figure 42. Power-On Reset to 0 V

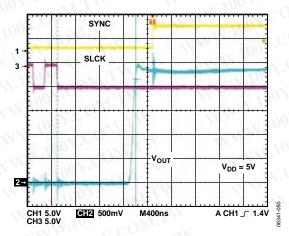


Figure 43. Exiting Power-Down to Midscale

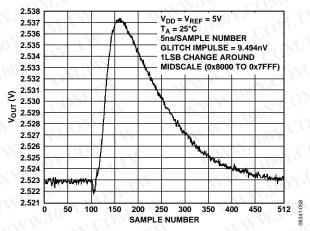


Figure 44. Digital-to-Analog Glitch Impulse (Negative)

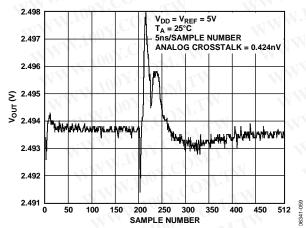


Figure 45. Analog Crosstalk, External Reference

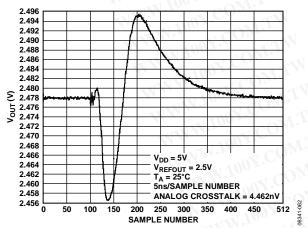


Figure 46. Analog Crosstalk, Internal Reference

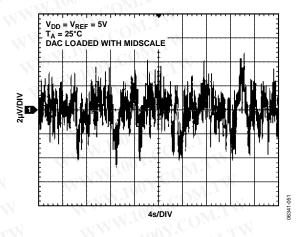


Figure 47. 0.1 Hz to 10 Hz Output Noise Plot, External Reference

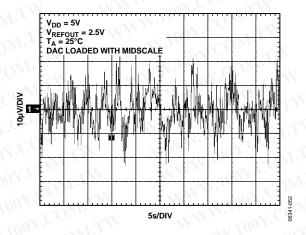


Figure 48. 0.1 Hz to 10 Hz Output Noise Plot, 2.5 V Internal Reference

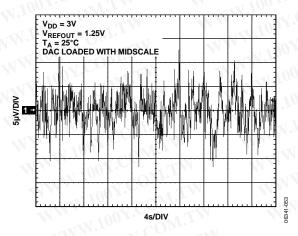


Figure 49. 0.1 Hz to 10 Hz Output Noise Plot, 1.25 V Internal Reference

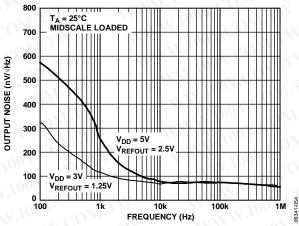


Figure 50. Noise Spectral Density, Internal Reference

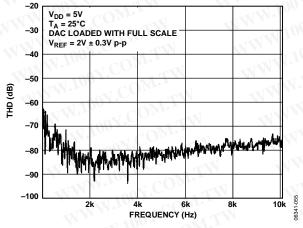


Figure 51. Total Harmonic Distortion

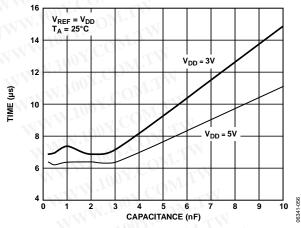


Figure 52. Settling Time vs. Capacitive Load

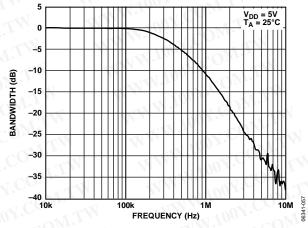


Figure 53. Multiplying Bandwidth

TERMINOLOGY

Relative Accuracy or Integral Nonlinearity (INL)

For the DAC, relative accuracy or integral nonlinearity is a measurement of the maximum deviation, in LSBs, from a straight line passing through the endpoints of the DAC transfer function.

Differential Nonlinearity (DNL)

Differential nonlinearity is the difference between the measured change and the ideal 1 LSB change between any two adjacent codes. A specified differential nonlinearity of ± 1 LSB maximum ensures monotonicity. This DAC is guaranteed monotonic by design.

Zero-Code Error

Zero-code error is a measurement of the output error when zero scale (0x0000) is loaded to the DAC register. Ideally, the output should be 0 V. The zero-code error is always positive in the AD5665R because the output of the DAC cannot go below 0 V due to a combination of the offset errors in the DAC and the output amplifier. Zero-code error is expressed in millivolts (mV).

Full-Scale Error

Full-scale error is a measurement of the output error when full-scale code (0xFFFF) is loaded to the DAC register. Ideally, the output should be $V_{\rm DD}-1$ LSB. Full-scale error is expressed as a percentage of full-scale range (FSR).

Gain Error

Gain error is a measure of the span error of the DAC. It is the deviation in slope of the DAC transfer characteristic from ideal expressed as a percentage of full-scale range (FSR).

Zero-Code Error Drift

Zero-code error drift is a measurement of the change in zero-code error with a change in temperature. It is expressed in microvolts per degrees Celsius ($\mu V/^{\circ}C$).

Gain Temperature Coefficient

Gain temperature coefficient is a measurement of the change in gain error with changes in temperature. It is expressed in parts per million (ppm) of full-scale range per degrees Celsius (FSR/°C).

Offset Error

Offset error is a measure of the difference between V_{OUT} (actual) and V_{OUT} (ideal) expressed in mV in the linear region of the transfer function. Offset error is measured on the AD5665R with Code 512 loaded in the DAC register. It can be negative or positive.

DC Power Supply Rejection Ratio (PSRR)

DC PSRR indicates how the output of the DAC is affected by changes in the supply voltage. PSRR is the ratio of the change in V_{OUT} to the change in V_{DD} for full-scale output of the DAC. It is measured in decibels (dB). V_{REF} is held at 2 V, and V_{DD} is varied by $\pm 10\%$.

Output Voltage Settling Time

Output voltage settling time is the amount of time it takes for the output of a DAC to settle to a specified level for a ¼ to ¾ full-scale input change, and it is measured from the rising edge of the stop condition.

Digital-to-Analog Glitch Impulse

Digital-to-analog glitch impulse is the impulse injected into the analog output when the input code in the DAC register changes state. It is normally specified as the area of the glitch in nV-s and is measured when the digital input code is changed by 1 LSB at the major carry transition (0x7FFF to 0x8000) (see Figure 44).

Digital Feedthrough

Digital feedthrough is a measure of the impulse injected into the analog output of the DAC from the digital inputs of the DAC but is measured when the DAC output is not updated. It is specified in nV-s and is measured with a full-scale code change on the data bus, that is, from all 0s to all 1s and vice versa.

Reference Feedthrough

Reference feedthrough is the ratio of the amplitude of the signal at the DAC output to the reference input when the DAC output is not being updated. It is expressed in decibels (dB).

Output Noise Spectral Density

Output noise spectral density is a measurement of the internally generated random noise, which is characterized as a spectral density (nanovolts per square root of hertz frequency (nV/\sqrt{Hz})). It is measured by loading the DAC to midscale and measuring noise at the output. It is measured in nanovolts per square root of hertz frequency (nV/\sqrt{Hz}). A plot of noise spectral density is shown in Figure 50.

DC Crosstalk

DC crosstalk is the dc change in the output level of one DAC in response to a change in the output of another DAC. It is measured with a full-scale output change on one DAC (or soft power-down and power-up) while monitoring another DAC kept at midscale. It is expressed in microvolts (μV).

DC crosstalk due to load current change is a measure of the impact that a change in load current on one DAC has on another DAC kept at midscale. It is expressed in microvolts per milliampere ($\mu V/mA$).

Digital Crosstalk

This is the glitch impulse transferred to the output of one DAC at midscale in response to a full-scale code change (all 0s to all 1s and vice versa) in the input register of another DAC. It is measured in standalone mode and is expressed in nanovolts per second (nV-s).

Analog Crosstalk

Analog crosstalk is the glitch impulse transferred to the output of one DAC due to a change in the output of another DAC. It is measured by loading one of the input registers with a full-scale code change (all 0s to all 1s and vice versa) and then executing a software LDAC and monitoring the output of the DAC whose digital code was not changed. The area of the glitch is expressed in nanovolts per second (nV-s).

DAC-to-DAC Crosstalk

DAC-to-DAC crosstalk is the glitch impulse transferred to the output of one DAC due to a digital code change and subsequent analog output change of another DAC. It is measured by loading the attack channel with a full-scale code change (all 0s to all 1s and vice versa) with $\overline{\text{LDAC}}$ low while monitoring the output of the victim channel that is at midscale. The energy of the glitch is expressed in nanovolts per second (nV-s).

Multiplying Bandwidth

The multiplying bandwidth is a measure of the finite bandwidth of the amplifiers within the DAC. A sine wave on the reference (with full-scale code loaded to the DAC) appears on the output. The multiplying bandwidth is the frequency at which the output amplitude falls to 3 dB below the input.

Total Harmonic Distortion (THD)

THD is the difference between an ideal sine wave and its attenuated version using the DAC. The sine wave is used as the reference for the DAC, and the THD is a measurement of the harmonics present on the DAC output. It is measured in decibels (dB).

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THEORY OF OPERATION

DIGITAL-TO-ANALOG CONVERTER (DAC)

The AD56x5R/AD56x5 DACs are fabricated on a CMOS process. The AD56x5 does not have an internal reference, and the DAC architecture is shown in Figure 54. The AD56x5R does have an internal reference and can be configured for use with either an internal or external reference (see Figure 54 and Figure 55).

Because the input coding to the DAC is straight binary, the ideal output voltage when using an external reference is given by

$$V_{OUT} = V_{REFIN} \times \left(\frac{D}{2^N}\right)$$

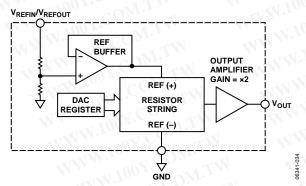


Figure 54. Internal Configuration When Using an External Reference

The ideal output voltage when using the internal reference is given by

$$V_{OUT} = 2 \times V_{REFOUT} \times \left(\frac{D}{2^N}\right)$$

where:

D is the decimal equivalent of the binary code that is loaded to the DAC register, as follows:

0 to 4095 for AD5625R/AD5625 (12-bit).

0 to 16,383 for AD5645R (14-bit).

0 to 65,535 for AD5665R/AD5665 (16-bit).

N is the DAC resolution.

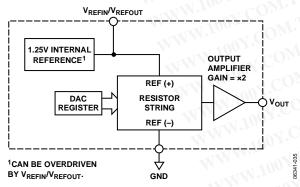


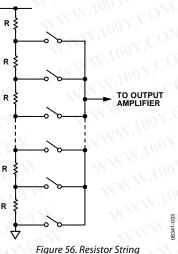
Figure 55. Internal Configuration When Using the Internal Reference

RESISTOR STRING

The resistor string is shown in Figure 56. It is simply a string of resistors, each of value R. The code loaded to the DAC register determines at which node on the string the voltage is tapped off to be fed into the output amplifier. The voltage is tapped off by closing one of the switches connecting the string to the amplifier. Because it is a string of resistors, it is guaranteed monotonic.

OUTPUT AMPLIFIER

The output buffer amplifier can generate rail-to-rail voltages on its output, which gives an output range of 0 V to $V_{\rm DD}.$ It can drive a load of 2 k Ω in parallel with 1000 pF to GND. The source and sink capabilities of the output amplifier are shown in Figure 38 and Figure 39. The slew rate is 1.8 V/µs with a ¼ to ¾ full-scale settling time of 7 µs.



INTERNAL REFERENCE

The AD5625R/AD5645R/AD5665R feature an on-chip reference. Versions without the R suffix require an external reference. The on-chip reference is off at power-up and is enabled via a write to a control register. See the Internal Reference Setup section for details.

Versions packaged in a 10-lead LFCSP have a 1.25 V reference or a 2.5 V reference, giving a full-scale output of 2.5 V or 5 V, depending on the model selected (see the Ordering Guide). These parts can be operated with a $V_{\rm DD}$ supply of 2.7 V to 5.5 V. Versions packaged in a 14-lead TSSOP have a 2.5 V reference, giving a full-scale output of 5 V. Parts are functional with a $V_{\rm DD}$ supply of 2.7 V to 5.5 V, but, with a $V_{\rm DD}$ supply of less than 5 V, the output is clamped to $V_{\rm DD}$. See the Ordering Guide for a full list of models. The internal reference associated with each part is available at the $V_{\rm REFOUT}$ pin (available on R suffix versions only).

A buffer is required if the reference output is used to drive external loads. When using the internal reference, it is recommended that a 100 nF capacitor be placed between the reference output and GND for reference stability.

EXTERNAL REFERENCE

The V_{REFIN} pin on the AD56x5R allows the use of an external reference if the application requires it. The default condition of the on-chip reference is off at power-up. All devices can be operated from a single 2.7 V to 5.5 V supply.

SERIAL INTERFACE

The AD56x5R/AD56x5 have 2-wire I²C-compatible serial interfaces. The AD56x5R/AD56x5 can be connected to an I²C bus as a slave device, under the control of a master device. See Figure 3 for a timing diagram of a typical write sequence.

The AD56x5R/AD56x5 support standard (100 kHz), fast (400 kHz), and high speed (3.4 MHz) data transfer modes. High speed operation is only available on selected models. See the Ordering Guide for a full list of models. Support is not provided for 10-bit addressing and general call addressing.

The AD56x5R/AD56x5 each has a 7-bit slave address. The 10-lead versions of the part have a slave address whose five MSBs are 00011, and the two LSBs are set by the state of the ADDR address pin, which determines the state of the A0 and A1 address bits. The 14-lead versions of the part have a slave address whose three MSBs are 001, and the four LSBs are set by the ADDR1 and ADDR2 address pins, which determine the state of the A0 and A1 and A2 and A3 address bits, respectively.

The facility to make hardwired changes to the ADDR pin allows the user to incorporate up to three of these devices on one bus, as outlined in Table 8.

Table 8. ADDR Pin Settings (10-Lead Package)

ADDR Pin Connection	A1TW	A0	
V_{DD}	COO	0	W
NC	N.100 P. CON. 1	0	
GND	1,00Y. 1,1TV	1	

The facility to make hardwired changes to the ADDR1 and the ADDR2 pins allows the user to incorporate up to nine of these devices on one bus, as outlined in Table 9.

Table 9. ADDR1, ADDR2 Pin Settings (14-Pin Package)

ADDR2 Pin Connection	ADDR1 Pin Connection	А3	A2	A1	AO
V _{DD}	V_{DD}	0	0	0	0
V_{DD}	NC	0	0	1	0
V_{DD}	GND	0	0	1.1	1711
NC	V_{DD}	1	0	0 0	0
NC	NC	1	0 10	1	0
NC	GND	1	0	11.	1, 1
GND	V_{DD}	1	1	0	0
GND	NC	1	1	101	0
GND	GND	1	1	101	1

The 2-wire serial bus protocol operates as follows:

- 1. The master initiates data transfer by establishing a start condition when a high-to-low transition on the SDA line occurs while SCL is high. The following byte is the address byte, which consists of the 7-bit slave address. The slave address corresponding to the transmitted address responds by pulling SDA low during the ninth clock pulse (this is termed the acknowledge bit). At this stage, all other devices on the bus remain idle while the selected device waits for data to be written to or read from its shift register.
- Data is transmitted over the serial bus in sequences of nine clock pulses (eight data bits followed by an acknowledge bit). The transitions on the SDA line must occur during the low period of SCL and remain stable during the high period of SCL.
- 3. When all data bits have been read or written, a stop condition is established. In write mode, the master pulls the SDA line high during the 10th clock pulse to establish a stop condition. In read mode, the master issues a no acknowledge for the ninth clock pulse (that is, the SDA line remains high). The master brings the SDA line low before the 10th clock pulse, and then high during the 10th clock pulse to establish a stop condition.

WRITE OPERATION

When writing to the AD56x5R/AD56x5, the user must begin with a start command followed by an address byte ($R/\overline{W}=0$), after which the DAC acknowledges that it is prepared to receive data by pulling SDA low. The AD5665 requires two bytes of data for the DAC and a command byte that controls various DAC functions. Three bytes of data must, therefore, be written to the DAC, the command byte followed by the most significant data byte and the least significant data byte, as shown in Figure 57 and Figure 58. After these data bytes are acknowledged by the AD56x5R/AD56x5, a stop condition follows.

READ OPERATION

When reading data back from the AD56x5R/AD56x5, the user begins with a start command followed by an address byte $(R/\overline{W}=1)$, after which the DAC acknowledges that it is prepared to transmit data by pulling SDA low. Two bytes of data are then read from the DAC, which are both acknowledged by the master as shown in Figure 59 and Figure 60. A stop condition follows.

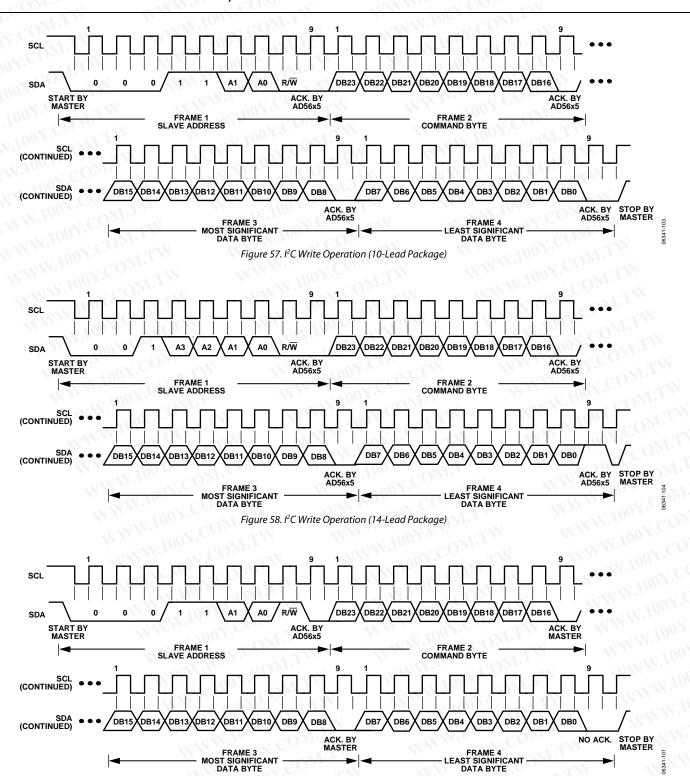


Figure 59. I²C Read Operation (10-Lead Package)

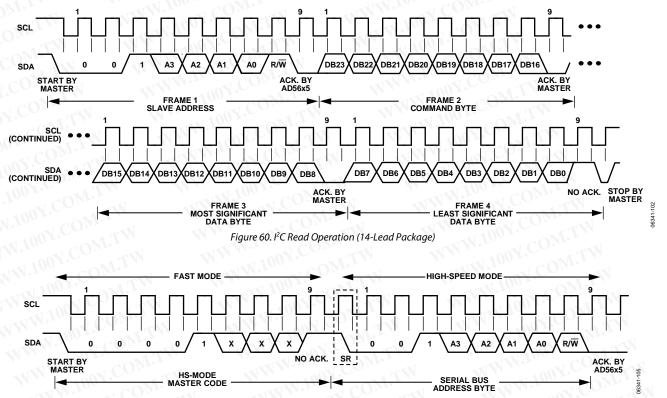


Figure 61. Placing the AD56x5RBRUZ-2/AD56x5RBRUZ-2REEL7 in High Speed Mode

HIGH SPEED MODE

Some models offer high speed serial communication with a clock frequency of 3.4 MHz. See the Ordering Guide for a full list of models.

High speed mode communication commences after the master addresses all devices connected to the bus with the Master Code 00001XXX to indicate that a high speed mode transfer is to begin. No device connected to the bus is permitted to acknowledge the high speed master code; therefore, the code is followed by a no acknowledge. Next, the master must issue a repeated start followed by the device address. The selected device then acknowledges its address. All devices continue to operate in high speed mode until the master issues a stop condition. When the stop condition is issued, the devices return to standard/fast mode. The part also returns to standard/fast mode when $\overline{\text{CLR}}$ is activated while the part is in high speed mode.

INPUT SHIFT REGISTER

The input shift register is 24 bits wide. Data is loaded into the device as a 24-bit word under the control of a serial clock input, SCL. The timing diagram for this operation is shown in Figure 3. The eight MSBs make up the command byte. DB23 is reserved and should always be set to 0 when writing to the device. DB22 (S) is used to select multiple byte operation. The next three bits are the command bits (C2, C1, and C0) that control the mode of operation of the device. See Table 10 for details. The last three bits of the first byte are the address bits (A2, A1, and A0). See Table 11 for details. The rest of the bits are the 16-/14-/12-bit data-word. The data-word comprises the 16-/14-/12-bit input code followed by two or four don't care bits for the AD5645R and the AD5625R/AD5625, respectively (see Figure 64 through Figure 66).

MULTIPLE BYTE OPERATION

Multiple byte operation is supported on the AD56x5R/AD56x5. A 2-byte operation is useful for applications that require fast DAC updating and do not need to change the command byte. The S bit (DB22) in the command register can be set to 1 for 2-byte mode of operation (see Figure 63). For standard 3-byte and 4-byte operation, the S bit (DB22) in the command byte should be set to 0 (see Figure 62).

ST SIGNIFICANT DATA BYTE
_

Figure 62. Multiple Block Write with Command Byte in Each Block (S = 0)

		BLOCK 1	1001.	BLO	CK 2 —	\mathbf{W}^{1}		OCK n
SLAVE ADDRESS	S = 1 COMMAND BYTE	MOST SIGNIFICANT DATA BYTE	LEAST SIGNIFICANT DATA BYTE	S = 1 MOST SIGNIFICANT DATA BYTE	LEAST SIGNIFICANT		S = 1 MOST SIGNIFICANT DATA BYTE	LEAST SIGNII

Figure 63. Multiple Block Write with Initial Command Byte Only (S = 1)

DB23	DB22	DB21	DB20	DB19	DB18	DB17	DB16	DB15	DB14	DB13	DB12	DB11	DB10	DB9	DB8	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB
R	S	C2	C1	CO	A2	A1	A0	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
SELECTION DAVE					DAC	ADDR	ESS	NY	NN.	100	DAC	DATA		N		W	WW	W.10	DAC	DATA	M. M	TW	ĺ
-15	UW.	С	ОММА	ND BY	E	- 1		_ <	TW	D	ATA HI	GH BY	ΓE	-TX		DATA LOW BYTE						N	

Figure 64. AD5665R/AD5665 Input Shift Register (16-Bit DAC)

DB23	DB22	DB21	DB20	DB19	DB18	DB17	DB16	DB15	DB14	DB13	DB12	DB11	DB10	DB9	DB8	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DBC
R	s	C2	C1	CO	A2	A1	A0	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0	Х	Х
RESERVED	COMMAND DAC ADDRESS					ESS	DAC DATA								DAC DATA								
		C	OMMA	ND BY1	E			N		D	ATA HI	GH BY	ΓE			DATA LOW BYTE							

)B23	DB22	DB21	DB20	DB19	DB18	DB17	DB16	DB15	DB14	DB13	DB12	DB11	DB10	DB9	DB8	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0
!	S	C2	C1	C0	A2	A1	A0	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0	X	X	Х	Х
NESENVED	O DAC ADDRESS					ESS	DAC DATA							DAC DATA							003		
		С	OMMA	ND BYT	E			DATA HIGH BYTE							DATA LOW BYTE								

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BROADCAST MODE

Broadcast addressing is supported on the AD56x5R/AD56x5 in write mode only. Broadcast addressing can be used to synchronously update or power down multiple AD56x5R/AD56x5 devices. When the broadcast address is used, the AD56x5R/AD56x5 responds regardless of the states of the address pins. The AD56x5R/AD56x5 broadcast address is 00010000.

Table 10. Command Definition

C2	C1	CO	Command
0	0	0	Write to input Register n
0	0	1	Update DAC Register n
0	100	0	Write to input Register n, update all (software LDAC)
0	11	1	Write to and update DAC Channel n
1	0	0	Power up/power down
1	0	1	Reset
1	1	0	LDAC register setup
1	1	1,0	Internal reference setup (on/off)

Table 11. DAC Address Command

A2 🕥	A1	A0	ADDRESS (n)	MM
0	0	0, 0	DAC A	THIN W. I
0	0	101	DAC B	
0	1	0	DAC C	
0	1	1	DAC D	
1	1	1001	All DACs	

LDAC FUNCTION

The AD56x5R/AD56x5 DACs have double-buffered interfaces consisting of two banks of registers: input registers and DAC registers. The input registers are connected directly to the input shift register, and the digital code is transferred to the relevant input register upon completion of a valid write sequence. The DAC registers contain the digital code used by the resistor strings.

Access to the DAC registers is controlled by the \overline{LDAC} pin. When the \overline{LDAC} pin is high, the DAC registers are latched and the input registers can change state without affecting the contents of the DAC registers. When \overline{LDAC} is brought low, however, the DAC registers become transparent and the contents of the input registers are transferred to them. The double-buffered interface is useful if the user requires simultaneous updating of all DAC outputs. The user can write to one of the input registers individually and then, by bringing \overline{LDAC} low when writing to the other DAC input register, all outputs update simultaneously.

These parts each contain an extra feature whereby a DAC register is not updated unless its input register has been updated since the last time $\overline{\text{LDAC}}$ was brought low. Normally, when $\overline{\text{LDAC}}$ is brought low, the DAC registers are filled with the contents of the input registers. In the case of the AD56x5R/AD56x5, the DAC register updates only if the input register has changed since the last time the DAC register was updated, thereby removing unnecessary digital crosstalk.

The outputs of all DACs can be simultaneously updated, using the hardware $\overline{\text{LDAC}}$ pin.

Synchronous LDAC

The DAC registers are updated after new data is read in. $\overline{\text{LDAC}}$ can be permanently low or pulsed.

Asynchronous LDAC

The outputs are not updated at the same time that the input registers are written to. When LDAC goes low, the DAC registers are updated with the contents of the input register.

The LDAC register gives the user full flexibility and control over the hardware LDAC pin (and software LDAC on the 10-lead parts that do not have the hardware LDAC pin—see Table 12). This register allows the user to select which combination of channels to simultaneously update when the hardware LDAC pin is executed. Setting the LDAC bit register to 0 for a DAC channel means that the update of this channel is controlled by the LDAC pin. If this bit is set to 1, this channel synchronously updates; that is, the DAC register is updated after new data is read in, regardless of the state of the LDAC pin. The device effectively sees the LDAC pin as being pulled low. See Table 13 for the LDAC register mode of operation. This flexibility is useful in applications when the user wants to simultaneously update select channels while the rest of the channels are synchronously updating.

Writing to the DAC using Command 110 loads the 4-bit $\overline{\text{LDAC}}$ register [DB3:DB0]. The default for each channel is 0; that is, the $\overline{\text{LDAC}}$ pin works normally. Setting the bits to 1 means that the DAC register is updated, regardless of the state of the $\overline{\text{LDAC}}$ pin. See Figure 67 for the contents of the input shift register during the $\overline{\text{LDAC}}$ register setup command.

Table 12. LDAC Register Mode of Operation on the 10-Lead LFCSP (Load DAC Register)

LDAC Bits (DB3 to DB0)	LDAC Mode of Operation
0	Normal operation (default), DAC register update is controlled by the write command.
1 V	The DAC registers are updated after new data is read in.

Table 13. LDAC Register Mode of Operation on the 14-Lead TSSOP (Load DAC Register)

LDAC Bits (DB3 to DB0)	LDAC Pin	LDAC Operation
0	1/0	Determined by the LDAC pin.
M. I. M.	x = don't care	The DAC registers are updated after new data is read in.

R	s	C2	C1	CO	A2	A1	A0	DB15	DB14	DB13	DB12	DB11	DB10	DB9	DB8	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0
0	Х	1	1	0	A2	A1	A0	х	Х	X	х	Х	х	Х	X	Х	Х	х	х	DAC D	DAC C	DAC B	DAC A
RESERVED	DON'T CARE	C	OMMAN	ID		ADDR N'T CA		CO	M.T	W	DON'T	CARE	WV	N.Y	100	y.C	DON'T	CARE	N	(0 = Ē	DAC S DAC PI		

Figure 67. LDAC Setup Command

POWER-DOWN MODES

Command 100 is reserved for the power-up/power-down function. The power-up/power-down modes are programmed by setting Bit DB5 and Bit DB4. This defines the output state of the DAC amplifier, as shown in Table 14. Bit DB3 to Bit DB0 determine to which DAC or DACs the power-up/power-down command is applied. Setting one of these bits to 1 applies the power-up/power-down state defined by DB5 and DB4 to the corresponding DAC. If a bit is 0, the state of the DAC is unchanged. Figure 69 shows the contents of the input shift register for the power-up/power-down command.

When Bit DB5 and Bit DB4 are set to 0, the part works normally with its normal power consumption of 1 mA at 5 V. However, for the three power-down modes, the supply current falls to 480 nA at 5 V. Not only does the supply current fall, but the output stage is also internally switched from the output of the amplifier to a resistor network of known values. This allows the output impedance of the part to be known while the part is in power-down mode. The outputs can either be connected internally to GND through a 1 k Ω or 100 k Ω resistor or be left open-circuited (three-state) as shown in Figure 66.

Note that the 14-lead TSSOP models offer the power-down function when the part is operated with a $V_{\rm DD}$ of 3.6 V to 5.5 V. The 10-lead LFCSP models offer the power-down function when the part is powered with a $V_{\rm DD}$ of 2.7 V to 5.5 V.

Table 14. Modes of Operation for the AD56x5R/AD56x5

DB5	DB4	Operating Mode
0	0	Normal operation
	1007	Power-down modes
0	1	1 kΩ pull-down resistor to GND
1	0 100	100 kΩ pull-down resistor to GND
1	1 10	Three-state, high impedance

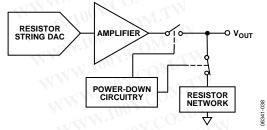


Figure 68. Output Stage During Power-Down

The bias generator, output amplifier, resistor string, and other associated linear circuitry are shut down when power-down mode is activated. However, the contents of the DAC register are unaffected when in power-down. The time to exit power-down is typically 4 μ s for $V_{DD} = 5$ V or $V_{DD} = 3$ V.

R	S	C2	C1	CO	A2	A1	A0	DB15	DB14	DB13	DB12	DB11	DB10	DB9	DB8	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0
0	Х	1	0	0	A2	A1	Α0	х	х	Х	х	х	X	Х	Х	х	х	PD1	PD0	DAC D	DAC C	DAC B	DAC A
RESERVED	DON'T		OMMAI	ND (C ADDR ON'T CA		N		V	DON'T	CARE	00 ⁷	CO V.C	OM	DON'T	CARE	POV	VER- I MODE	(1 :	DAC S	SELECT SELECT	

Figure 69. Power-Up/Power-Down Command

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POWER-ON RESET AND SOFTWARE RESET

The AD56x5R/AD56x5 contain a power-on reset circuit that controls the output voltage during power-up. The 10-lead version of the device powers up to 0 V. The 14-lead version has a power-on reset (POR) pin that allows the output voltage to be selected. By connecting the POR pin to GND, the AD56x5R/AD56x5 output powers up to 0 V; by connecting the POR pin to $V_{\rm DD}$, the AD56x5R/AD56x5 output powers up to midscale. The output remains powered up at this level until a valid write sequence is made to the DAC. This is useful in applications where it is important to know the state of the output of the DAC while it is in the process of powering up.

Any events on LDAC or CLR during power-on reset are ignored.

There is also a software reset function. Command 101 is the software reset command. The software reset command contains two reset modes that are software programmable by setting bit DB0 in the input shift register.

Table 15 shows how the state of the bit corresponds to the software reset modes of operation of the devices. Figure 70 shows the contents of the input shift register during the software reset mode of operation.

Table 15. Software Reset Modes for the AD56x5R/AD56x5

DB0	Registers Reset to Zero
0	DAC register
	Input shift register
1 (Power-On Reset)	DAC register
	Input shift register
	LDAC register
	Power-down register
	Internal reference setup register

INTERNAL REFERENCE SETUP (R VERSIONS)

The on-chip reference is off at power-up by default. It can be turned on by sending the reference setup command (111) and setting DB0 in the input shift register. Table 16 shows how the state of the bit corresponds to the mode of operation.

Table 16. Reference Setup Command

DB0	Action
0	Internal reference off (default)
1	Internal reference on

х	s	C2	C1	CO	A2	A1	A0	DB15	DB14	DB13	DB12	DB11	DB10	DB9	DB8	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0
0	х	1	0	(1)	х	_X	х	х	х	х	х	х	Х	X	х	х	х	х	Х	х	х	X	RST
RESERVED	DON'T CARE	c	OMMAI	ND		C ADDR				1	DON'T	CARE	700, 00 x	1.C ⁽	OM:	TV	I	DC	ON'T CA	ARE	.100 N.10	0Y.	RESET

Figure 70. Reset Command

R	s	C2	C1	CO	A2	A1	A0	DB15	DB14	DB13	DB12	DB11	DB10	DB9	DB8	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0
0	х	1	1	1	Х	X	х	х	X	х	х	х	х	X	х	х	X	х	х	х	х	х	REF
RESERVED	DON'T CARE	C	OMMAN	Ð		C ADDR ON'T CA			LT.	N	DON'T	CARE	NN.	N.1	1007 1007		M. Mo	D	ON'T C	ARE	W	NV.	REFERENCE MODE

Figure 71. Reference Setup Command

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APPLICATIONS INFORMATION

USING A REFERENCE AS A POWER SUPPLY FOR THE AD56x5R/AD56x5

Because the supply current required by the AD56x5R/AD56x5 is extremely low, an alternative option is to use a voltage reference to supply the required voltage to the part (see Figure 72). This is especially useful if the power supply is noisy or if the system supply voltages are at some value other than 5 V or 3 V, for example, 15 V. The voltage reference outputs a steady supply voltage for the AD56x5R/AD56x5. If the low dropout REF195 is used, it must supply 450 μA of current to the AD56x5R/AD56x5 with no load on the output of the DAC. When the DAC output is loaded, the REF195 also must supply the current to the load. The total current required (with a 5 k Ω load on the DAC output) is

$$1 \text{ mA} + (5 \text{ V}/5 \text{ k}\Omega) = 2 \text{ mA}$$

The load regulation of the REF195 is typically 2 ppm/mA, resulting in a 4 ppm (20 μ V) error for the 2 mA current drawn from it. This corresponds to a 0.263 LSB error.

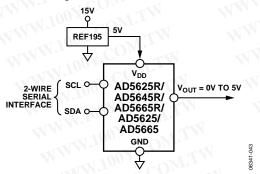


Figure 72. REF195 as Power Supply to the AD56x5R/AD56x5

BIPOLAR OPERATION USING THE AD56x5R/AD56x5

The AD56x5R/AD56x5 have been designed for single-supply operation, but a bipolar output range is also possible using the circuit shown in Figure 73. The circuit gives an output voltage range of ± 5 V. Rail-to-rail operation at the amplifier output is achievable using an AD820 or an OP295 as the output amplifier.

The output voltage for any input code can be calculated as follows:

$$V_{O} = \left[V_{DD} \times \left(\frac{D}{65,536} \right) \times \left(\frac{RI + R2}{RI} \right) - V_{DD} \times \left(\frac{R2}{RI} \right) \right]$$

where *D* represents the input code in decimal (0 to 65,535). If $V_{DD} = 5 \text{ V}$, $R1 = R2 = 10 \text{ k}\Omega$,

$$V_{\rm O} = \left(\frac{10 \times D}{65,536}\right) - 5 \text{ V}$$

This is an output voltage range of ± 5 V, with 0x0000 corresponding to a -5 V output and 0xFFFF corresponding to a +5 V output.

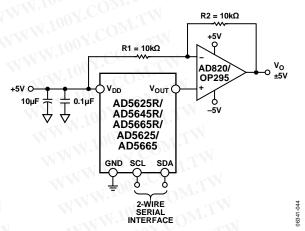


Figure 73. Bipolar Operation with the AD56x5R/AD56x5

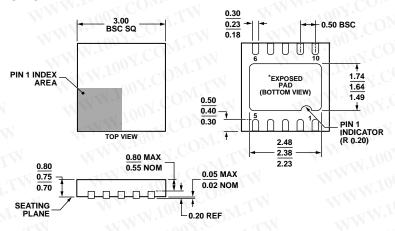
POWER SUPPLY BYPASSING AND GROUNDING

When accuracy is important in a circuit, it is helpful to carefully consider the power supply and ground return layout on the board. The printed circuit board containing the AD56x5R/AD56x5 should have separate analog and digital sections, each having its own area of the board. If the AD56x5R/AD56x5 are in a system where other devices require an AGND-to-DGND connection, the connection should be made at one point only. This ground point should be as close as possible to the AD56x5R/AD56x5.

The power supply to the AD56x5R/AD56x5 should be bypassed with 10 μF and 0.1 μF capacitors. The capacitors should be located as close as possible to the device, with the 0.1 μF capacitor ideally right up against the device. The 10 μF capacitor is the tantalum bead type. It is important that the 0.1 μF capacitor have low effective series resistance (ESR) and low effective series inductance (ESI), for example, common ceramic types of capacitors. This 0.1 μF capacitor provides a low impedance path to ground for high frequencies caused by transient currents due to internal logic switching.

The power supply line itself should have as large a trace as possible to provide a low impedance path and to reduce glitch effects on the supply line. Clocks and other fast switching digital signals should be shielded from other parts of the board by digital ground. Avoid crossover of digital and analog signals if possible. When traces cross on opposite sides of the board, ensure that they run at right angles to each other to reduce feedthrough effects through the board. The best board layout technique is the microstrip technique where the component side of the board is dedicated to the ground plane only, and the signal traces are placed on the solder side. However, this is not always possible with a 2-layer board.

OUTLINE DIMENSIONS



*FOR PROPER CONNECTION OF THE EXPOSED PAD PLEASE REFER TO THE PIN CONFIGURATION AND FUNCTION DESCRIPTIONS SECTION OF THIS DATA SHEET.

Figure 74. 10-Lead Lead Frame Chip Scale Package [LFCSP_WD] 3 mm × 3 mm Body, Very Very Thin, Dual Lead (CP-10-9) Dimensions shown in millimeters

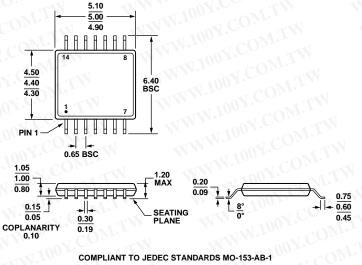


Figure 75. 14-Lead Thin Shrink Small Outline Package [TSSOP] (RU-14) Dimensions shown in millimeters

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ORDERING GUIDE

Model ¹	Temperature Range	Accuracy	On-Chip Reference	Maximum I ² C Speed	Package Description	Package Option	Brandin
AD5625BCPZ-R2	-40°C to +105°C	±1 LSB INL	None	400 kHz	10-Lead LFCSP_WD	CP-10-9	D8V
AD5625BCPZ-REEL7	-40°C to +105°C	±1 LSB INL	None	400 kHz	10-Lead LFCSP_WD	CP-10-9	D8V
AD5625BRUZ	-40°C to +105°C	±1 LSB INL	None	400 kHz	14-Lead TSSOP	RU-14	
AD5625BRUZ-REEL7	-40°C to +105°C	±1 LSB INL	None	400 kHz	14-Lead TSSOP	RU-14	
AD5625RBCPZ-R2	-40°C to +105°C	±1 LSB INL	1.25 V	400 kHz	10-Lead LFCSP_WD	CP-10-9	D8S
AD5625RBCPZ-REEL7	-40°C to +105°C	±1 LSB INL	1.25 V	400 kHz	10-Lead LFCSP_WD	CP-10-9	D8S
AD5625RACPZ-REEL7	-40°C to +105°C	±4 LSB INL	1.25 V	400 kHz	10-Lead LFCSP_WD	CP-10-9	DEU
AD5625RACPZ-1RL7	-40°C to +105°C	±4 LSB INL	2.5 V	400 kHz	10-Lead LFCSP_WD	CP-10-9	DFW
AD5625RBRUZ-1	-40°C to +105°C	±1 LSB INL	2.5 V	400 kHz	14-Lead TSSOP	RU-14	
AD5625RBRUZ-1REEL7	-40°C to +105°C	±1 LSB INL	2.5 V	400 kHz	14-Lead TSSOP	RU-14	
AD5625RBRUZ-2	-40°C to +105°C	±1 LSB INL	2.5 V	3.4 MHz	14-Lead TSSOP	RU-14	
AD5625RBRUZ-2REEL7	-40°C to +105°C	±1 LSB INL	2.5 V	3.4 MHz	14-Lead TSSOP	RU-14	
AD5645RBCPZ-R2	-40°C to +105°C	±4 LSB INL	1.25 V	400 kHz	10-Lead LFCSP_WD	CP-10-9	D89
AD5645RBCPZ-REEL7	-40°C to +105°C	±4 LSB INL	1.25 V	400 kHz	10-Lead LFCSP_WD	CP-10-9	D89
AD5645RBRUZ	-40°C to +105°C	±4 LSB INL	2.5 V	400 kHz	14-Lead TSSOP	RU-14	
AD5645RBRUZ-REEL7	-40°C to +105°C	±4 LSB INL	2.5 V	400 kHz	14-Lead TSSOP	RU-14	
AD5665BCPZ-R2	-40°C to +105°C	±16 LSB INL	None	400 kHz	10-Lead LFCSP_WD	CP-10-9	D6U
AD5665BCPZ-REEL7	-40°C to +105°C	±16 LSB INL	None	400 kHz	10-Lead LFCSP_WD	CP-10-9	D6U
AD5665BRUZ	-40°C to +105°C	±16 LSB INL	None	400 kHz	14-Lead TSSOP	RU-14	
AD5665BRUZ-REEL7	-40°C to +105°C	±16 LSB INL	None	400 kHz	14-Lead TSSOP	RU-14	TW
AD5665RBCPZ-R2	-40°C to +105°C	±16 LSB INL	1.25 V	400 kHz	10-Lead LFCSP_WD	CP-10-9	DA2
AD5665RBCPZ-REEL7	-40°C to +105°C	±16 LSB INL	1.25 V	400 kHz	10-Lead LFCSP_WD	CP-10-9	DA2
AD5665RBRUZ-1	-40°C to +105°C	±16 LSB INL	2.5 V	400 kHz	14-Lead TSSOP	RU-14	WIIM
AD5665RBRUZ-1REEL7	-40°C to +105°C	±16 LSB INL	2.5 V	400 kHz	14-Lead TSSOP	RU-14	TW
AD5665RBRUZ-2	-40°C to +105°C	±16 LSB INL	2.5 V	3.4 MHz	14-Lead TSSOP	RU-14	OW.
AD5665RBRUZ-2REEL7	-40°C to +105°C	±16 LSB INL	2.5 V	3.4 MHz	14-Lead TSSOP	RU-14	OM.T'
EVAL-AD5665REBZ1	100X.COM	W	WWW	ON.COS	TSSOP Evaluation Board	W.100Y.	COM
EVAL-AD5665REBZ2	· TOOX COM	WI	WWW	100 A . CO.	LFCSP Evaluation Board	W.1007	COM

¹ Z = RoHS Compliant Part.

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I²C refers to a communications protocol originally developed by Philips Semiconductors (now NXP Semiconductors).



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